

SB007W03Q

Schottky Barrier Diode (Twin Type - Cathode Common)

30V, 70mA Rectifier

Applications

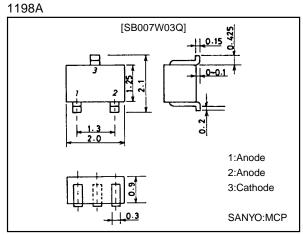
• High frequency rectification (switching regulators, converters, choppers).

Features

- · Low forward voltage (V_F max=0.55V).
- · Fast reverse recovery time (t_{rr} max=10ns).
- · Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.
- · Ultrasmall-sized package permitting SB007W03Qapplied sets to be made small and slim.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	V
Non-repetitive Peak Reverse Surge Voltage	V _{RSM}		35	V
Average Output Current	I _O		70	mA
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	2	A
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta = 25°C

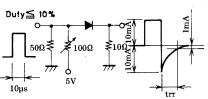
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	VR	I _R =20µA	30			V
Forward Voltage	VF	I _F =70mA			0.55	V
Reverse Current	۱ _R	V _R =15V			5	μA
Interterminal Capacitance	С	V _R =10V, f=1MHz		3.0		pF
Reverse Recovery Time	t _{rr}	I _F =I _R =10mA, See specified Test Circuit			10	ns

2

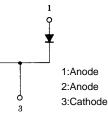
q

Marking : K

t_{rr} Test Circuit

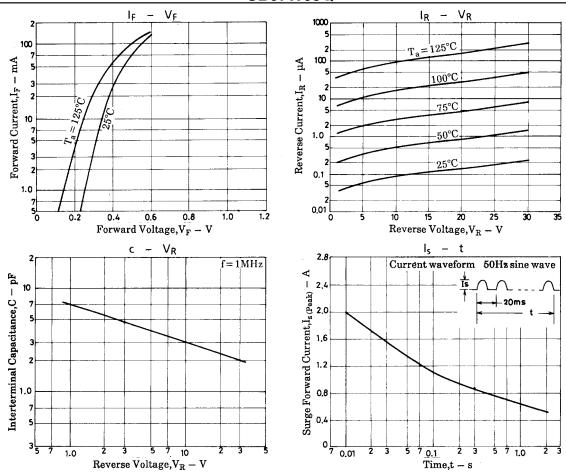


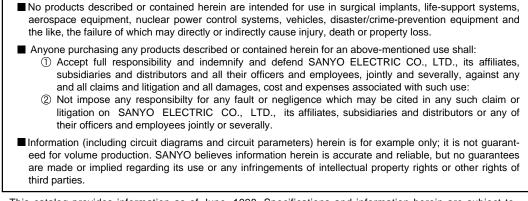
Electrical Connection



SANYO Electric Co., Ltd. Semiconductor Bussiness Headquarters TOKYO OFFICE, Tokyo Bldg., 1-10, Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

62098HA (KT)/D1096GI/1269TA, TS No.2938-1/2





This catalog provides information as of June, 1998. Specifications and information herein are subject to change without notice.

PS No.2938-2/2